## NSN 5962-01-230-8403

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## **Body Length:** 1.290 inches **Body Width:** Between 0.500 inches and 0.610 inches **Body Height:** 0.210 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0 to 125.0 degrees celsius Storage Tempurature Range: -65.0 to 125.0 degrees celsius **End Application:** 6625-01-211-9471 tester, digital **Features Provided:** Monolithic and ultraviolet erasable and w/enable **Inclosure Material:** Ceramic and glass Inclosure Configuration: Dual-in-line **Output Logic Form:** N-type metal oxide-semiconductor logic **Input Circuit Pattern:** 14 input **Case Outline Source And Designator:** D-3 mil-m-38510 **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -0.3 volts power source and 6.0 volts power source **Time Rating Per Chacteristic:** 450.00 nanoseconds propagation delay time, low to high level output and 450.00 nanoseconds propagation delay time, high to low level output Memory Device Type: Rom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a Unit Of Measure:

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## Demilitarization:

Yes - demil/mli

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